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Fax Cover Sheet

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Message

DOCKET GS 134

Please see attached **Response to Restriction Requirement**.

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Hshieh et al.
Serial No.: 09/881,254
Filed: June 14, 2001
Title: Symmetric Trench MOSFET Device and Method of Making Same
Art Unit: 2826
Examiner: Johannes P. Mondt
Docket No.: GS 134

Assistant Commissioner for Patents
Washington, D.C. 20231

RESPONSE TO RESTRICTION REQUIREMENT

Sir:

In response to the Office Action dated January 9, 2002 (Paper No. 3), kindly consider the following response to the outstanding restriction requirement.

REMARKS

Claims 1-24 are pending in the application. Restriction was required to the following allegedly distinct inventions:

- I. Claims 1-16, drawn to a field effect transistor, classified in class 257, subclass 213.
- II. Claims 17-24, drawn to a method of making a field effect device, classified in class 438, subclass 192.